



SANYO Semiconductors

# DATA SHEET

An ON Semiconductor Company

## 2SA1419/2SC3649 — High-Voltage Switching Applications

PNP / NPN Epitaxial Planar Silicon Transistor

### Features

- Adoption of FBET, MBIT processes
- High breakdown voltage and large current capacity
- Ultrasmall size making it easy to provide high-density, small-sized hybrid IC's

### Specifications ( ) : 2SA1419

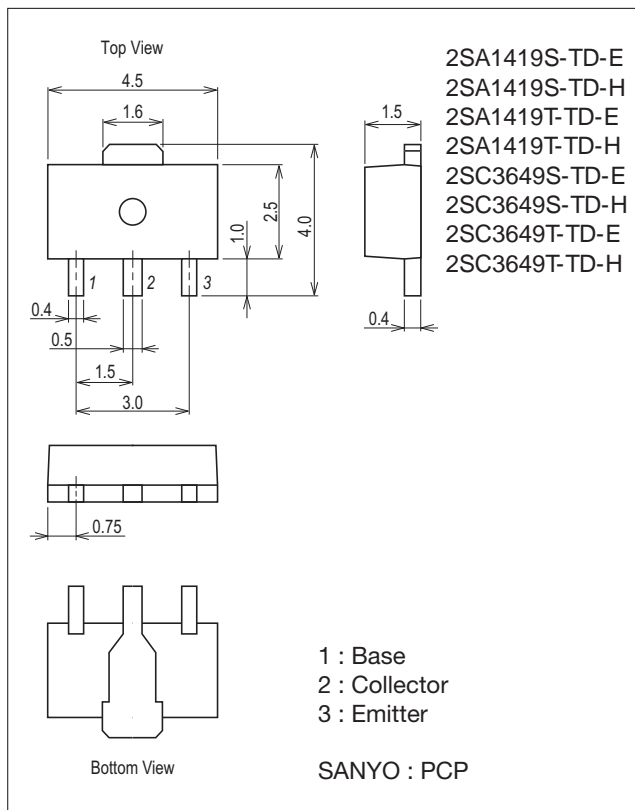
Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V <sub>CBO</sub>		(-)180	V
Collector-to-Emitter Voltage	V <sub>CEO</sub>		(-)160	V
Emitter-to-Base Voltage	V <sub>EBO</sub>		(-)6	V
Collector Current	I <sub>C</sub>		(-)1.5	A
Collector Current (Pulse)	I <sub>CP</sub>		(-)2.5	A
Collector Dissipation	P <sub>C</sub>		500	mW
		When mounted on ceramic substrate (250mm <sup>2</sup> ×0.8mm)	1.5	W
Junction Temperature	T <sub>J</sub>		150	°C
Storage Temperature	T <sub>stg</sub>		-55 to +150	°C

### Package Dimensions

unit : mm (typ)

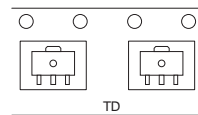
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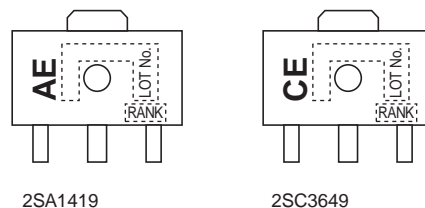
### Product & Package Information

- Package : PCP
- JEITA, JEDEC : SC-62, SOT-89, TO-243
- Minimum Packing Quantity : 1,000 pcs./reel

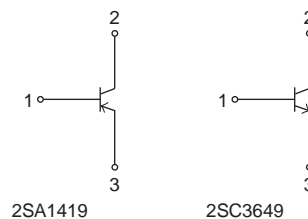
### Packing Type: TD



### Marking



### Electrical Connection



## 2SA1419 / 2SC3649

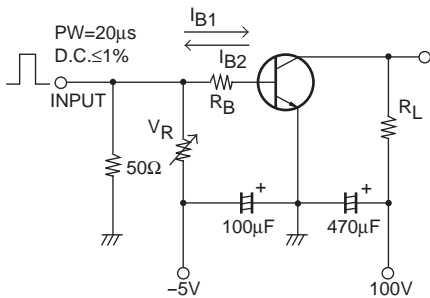
### Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	ICBO	V <sub>CB</sub> =(-)120V, I <sub>E</sub> =0A			(-)1	μA
Emitter Cutoff Current	IEBO	V <sub>EB</sub> =(-)4V, I <sub>C</sub> =0A			(-)1	μA
DC Current Gain	h <sub>FE1</sub>	V <sub>CE</sub> =(-)5V, I <sub>C</sub> =(-)100mA	100*		400*	
	h <sub>FE2</sub>	V <sub>CE</sub> =(-)5V, I <sub>C</sub> =(-)10mA	80			
Gain-Bandwidth Product	f <sub>T</sub>	V <sub>CE</sub> =(-)10V, I <sub>C</sub> =(-)50mA		120		MHz
Output Capacitance	C <sub>ob</sub>	V <sub>CB</sub> =(-)10V, f=1MHz		(22)14		pF
Collector-to-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =(-)500mA, I <sub>B</sub> =(-)50mA		(-200)130	(-500)450	mV
Base-to-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	I <sub>C</sub> =(-)500mA, I <sub>B</sub> =(-)50mA		(-)0.85	(-)1.2	V
Collector-to-Base Breakdown Voltage	V <sub>(BR)CBO</sub>	I <sub>C</sub> =(-)10μA, I <sub>E</sub> =0A	(-)180			V
Collector-to-Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>	I <sub>C</sub> =(-)1mA, R <sub>BE</sub> =∞	(-)160			V
Emitter-to-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> =(-)10μA, I <sub>C</sub> =0A	(-)6			V
Turn-ON Time	t <sub>on</sub>	See specified Test Circuit.		(40)40		ns
Storage Time	t <sub>stg</sub>			(0.7)1.2		μs
Fall Time	t <sub>f</sub>			(40)80		ns

\* : The 2SA1419 / 2SC3649 are classified by 100mA h<sub>FE</sub> as follows :

Rank	R	S	T
h <sub>FE</sub>	100 to 200	140 to 280	200 to 400

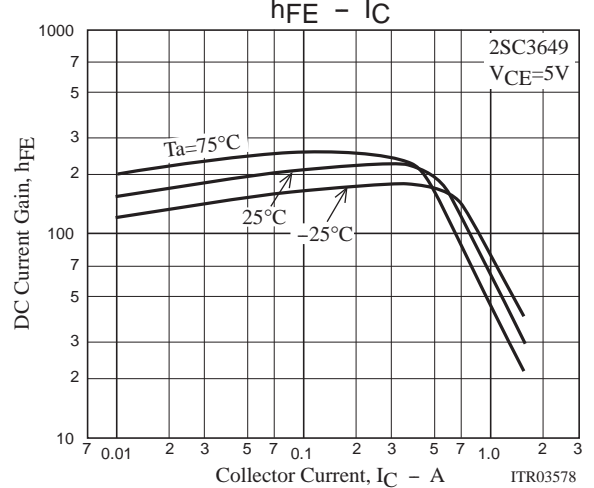
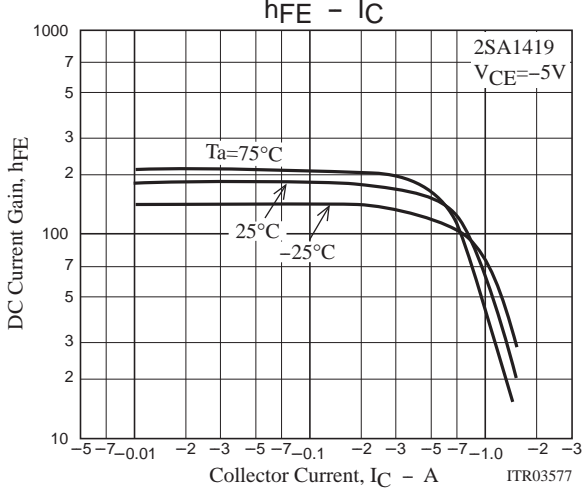
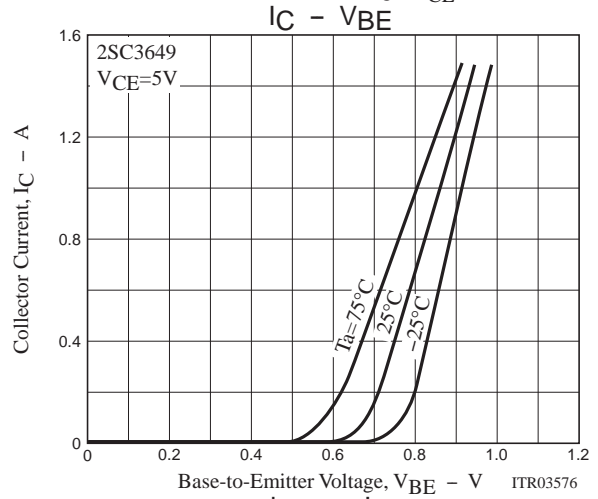
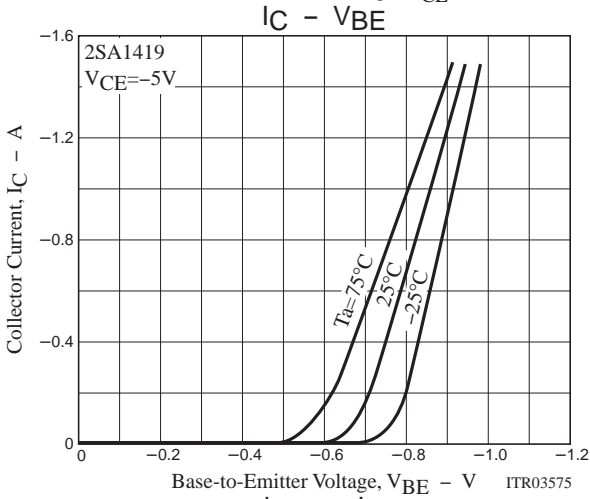
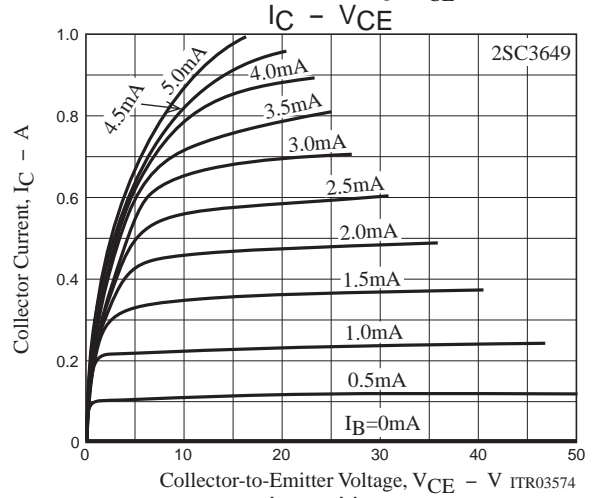
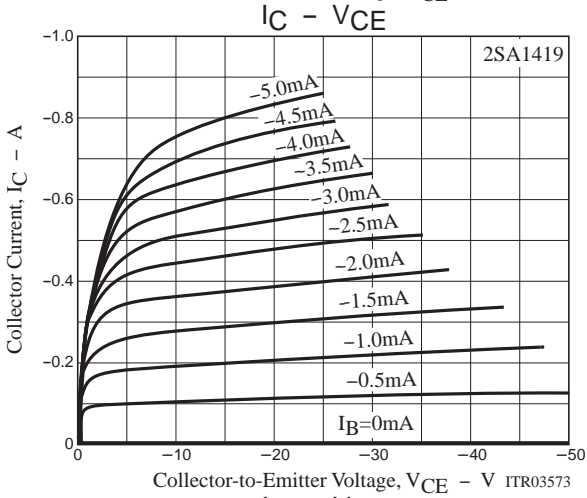
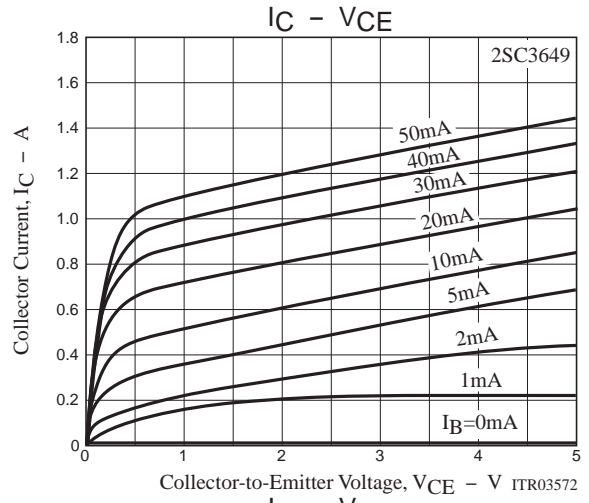
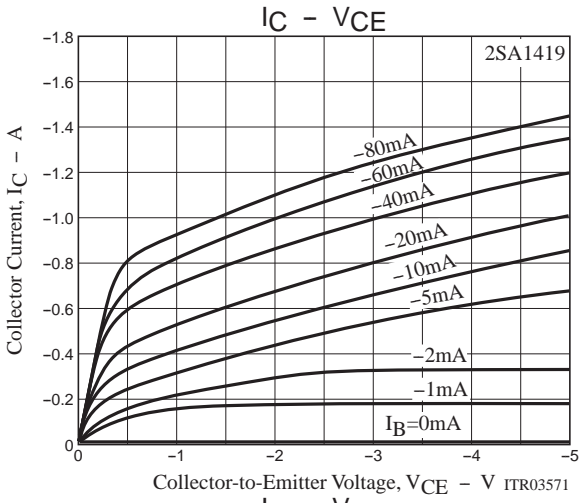
### Switching Time Test Circuit



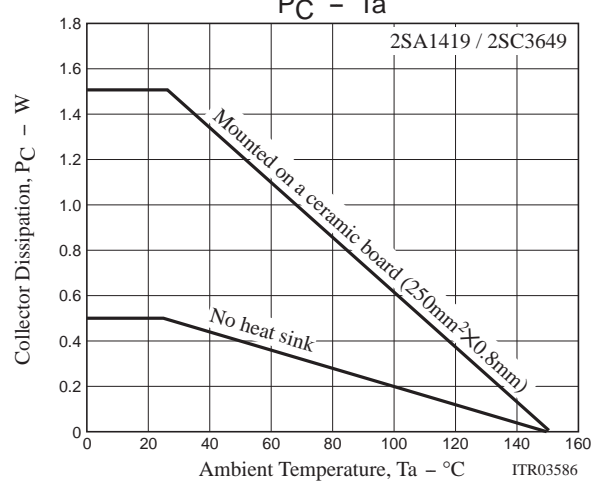
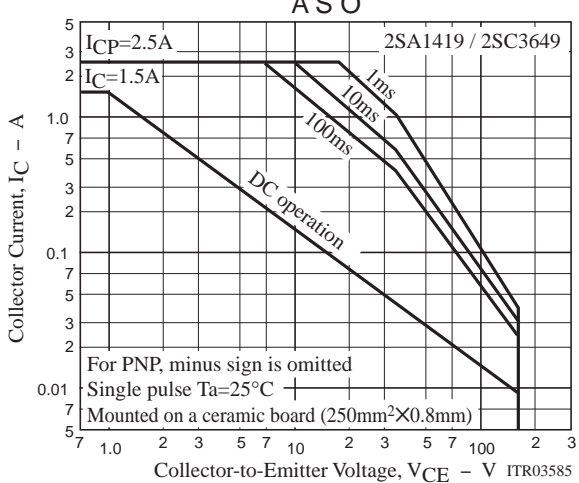
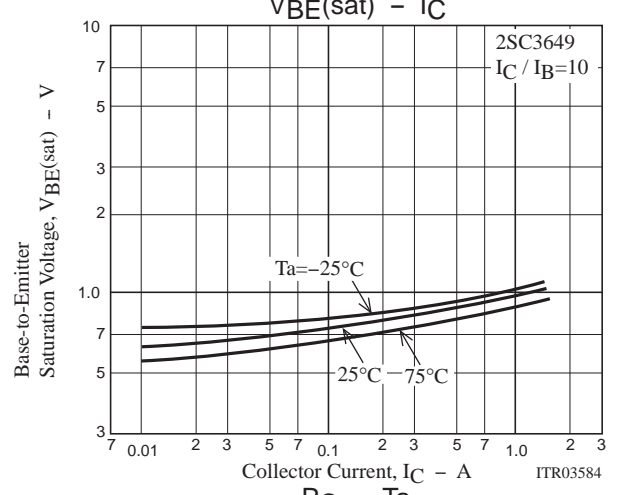
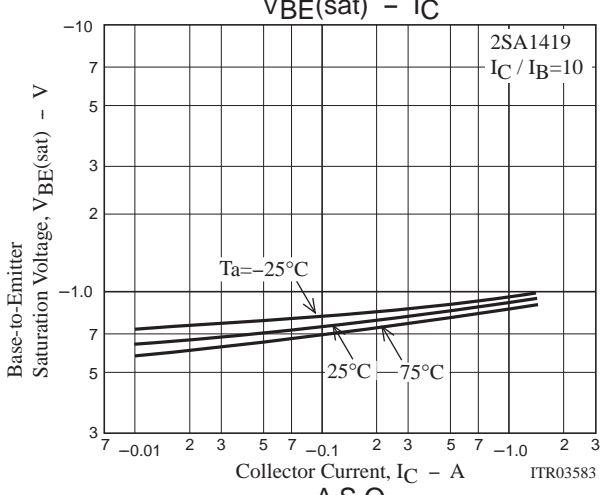
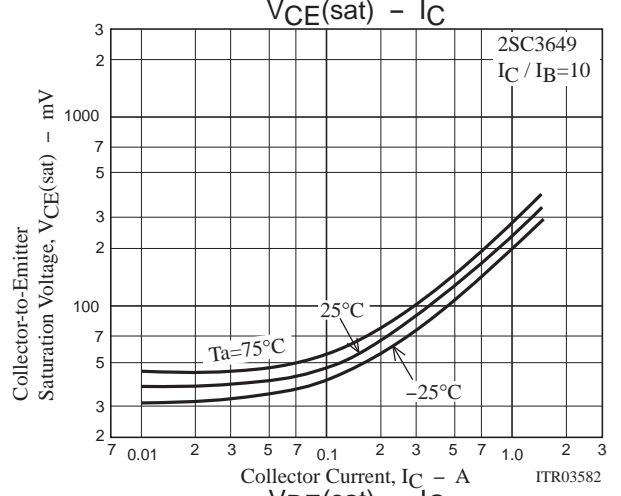
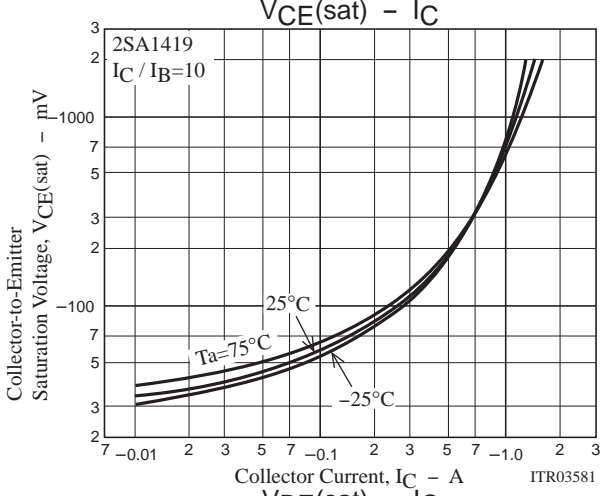
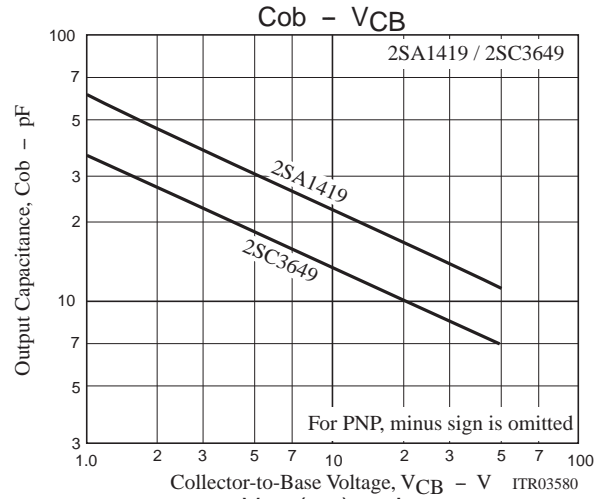
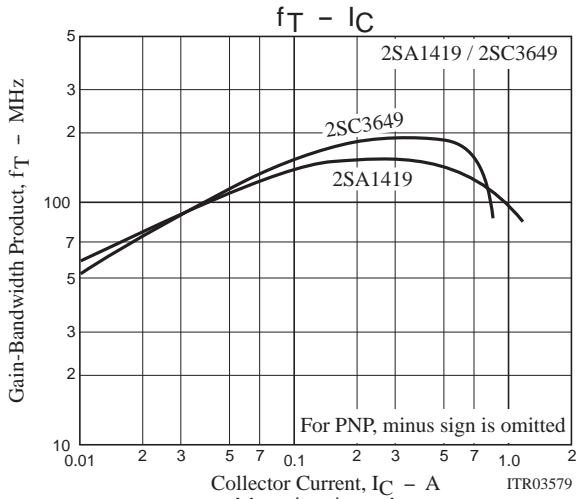
$I_C = 10I_{B1} = -10I_{B2} = 0.7A$   
 (For PNP, the polarity is reversed)

### Ordering Information

Device	Package	Shipping	memo
2SA1419S-TD-E	PCP	1,000pcs./reel	Pb Free
2SA1419S-TD-H	PCP	1,000pcs./reel	Pb Free and Halogen Free
2SA1419T-TD-E	PCP	1,000pcs./reel	Pb Free
2SA1419T-TD-H	PCP	1,000pcs./reel	Pb Free and Halogen Free
2SC3649S-TD-E	PCP	1,000pcs./reel	Pb Free
2SC3649S-TD-H	PCP	1,000pcs./reel	Pb Free and Halogen Free
2SC3649T-TD-E	PCP	1,000pcs./reel	Pb Free
2SC3649T-TD-H	PCP	1,000pcs./reel	Pb Free and Halogen Free



2SA1419 / 2SC3649



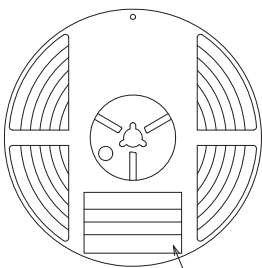
**Bag Packing Specification**

2SA1419S-TD-E, 2SA1419S-TD-H, 2SA1419T-TD-E, 2SA1419T-TD-H, 2SC3649S-TD-E, 2SC3649S-TD-H, 2SC3649T-TD-E, 2SC3649T-TD-H

1. Packing Format

Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
PCP	PCP	1,000	4,000	24,000	4 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

Packing method



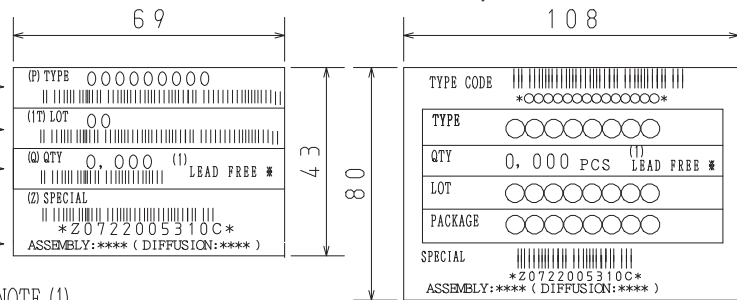
Type No.  
LOT No.  
Quantity  
Origin

Reel label

Reel label, Inner box label  
(unit:mm)

Outer box label

It is a label at the time of factory shipments.  
The form of a label may change in physical distribution process.



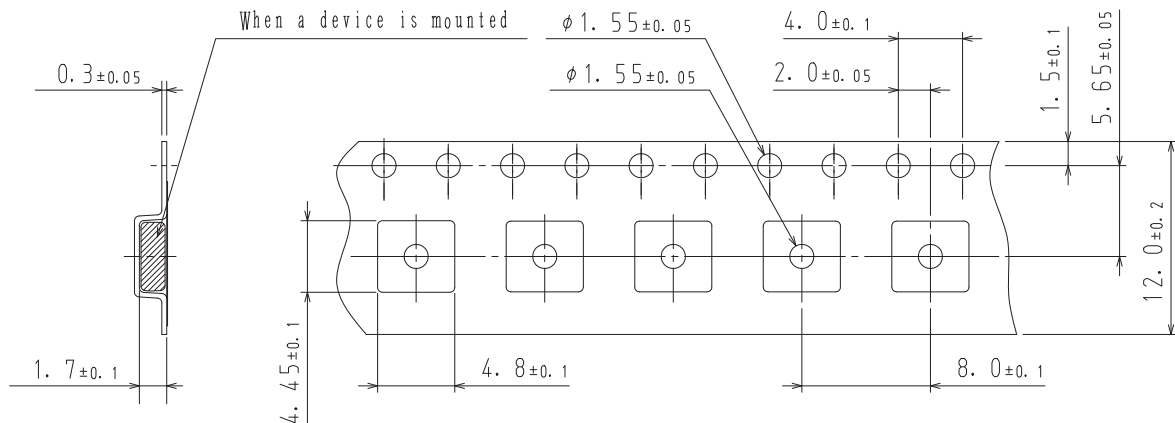
NOTE (1)

The LEAD FREE \* description shows that the surface treatment of the terminal is lead free,

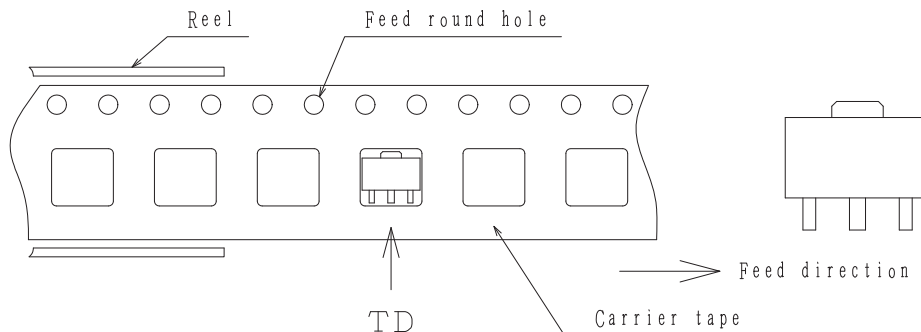
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

2. Taping configuration

2-1. Carrier tape size (unit:mm)



2-2. Device placement direction

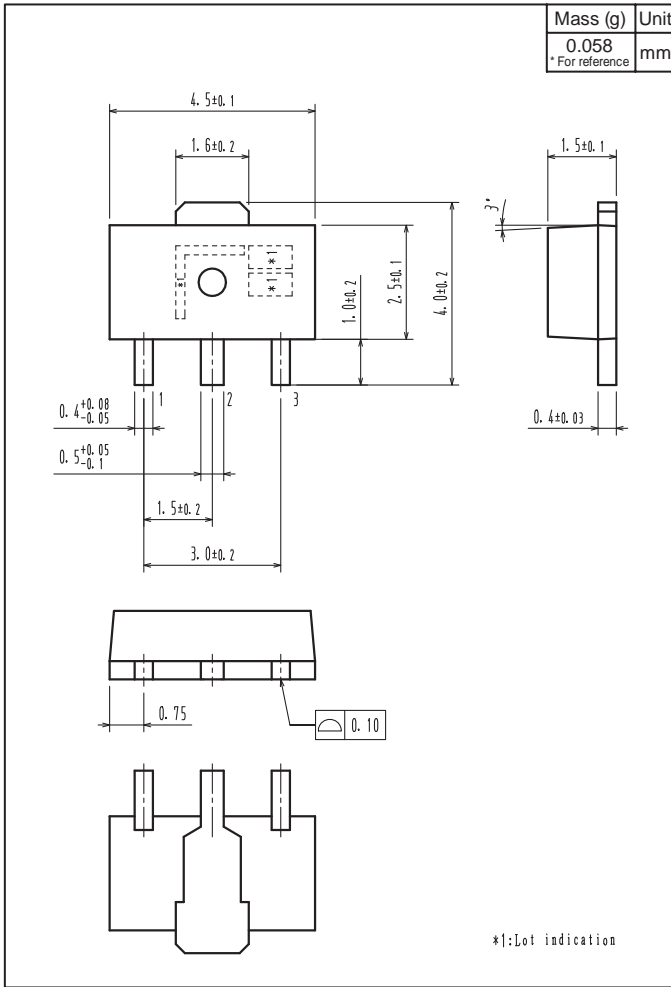


Those with pin 1 index on the feed hole side.....TD

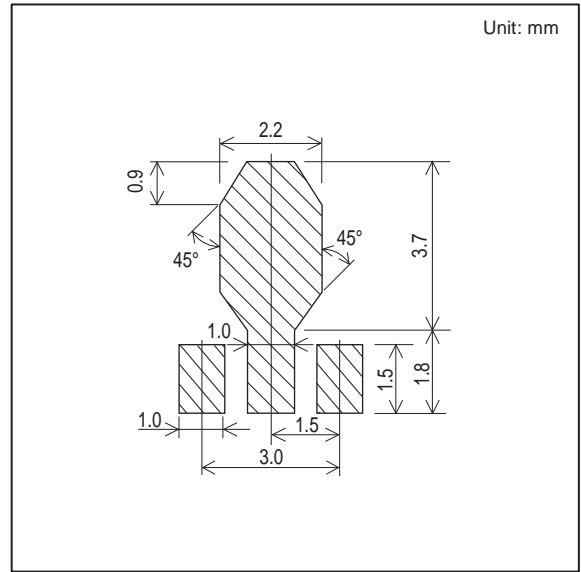
# 2SA1419 / 2SC3649

## Outline Drawing

2SA1419S-TD-E, 2SA1419S-TD-H, 2SA1419T-TD-E, 2SA1419T-TD-H, 2SC3649S-TD-E, 2SC3649S-TD-H, 2SC3649T-TD-E, 2SC3649T-TD-H



## Land Pattern Example



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